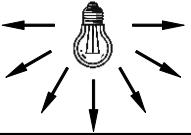


Quantity	Definition	Explanation
Light flux Φ 	$\Phi = K_m \int \phi_{el} V(\lambda) d\lambda$ unit: lumen, lm $K = 683 \text{ lm/W}$	The luminous flux is the V(lamda) weighted radiant flux.
Illuminance E 	$E = \frac{\Phi}{A}$ unit: lux, lx, lm/m ²	Illuminance is the quotient of the luminous flux incident on a surface element to the surface area. It does not matter from which direction the irradiation occurs.
Luminance L 	$L = \frac{\Phi}{A_p \omega}$ unit: lm/(sr m ²), cd/m ²	The luminance of a surface element A_p is the quotient of the emitted luminous flux to the product of the surface element and the solid angle.
Luminous intensity I 	$I = \frac{\Phi}{\omega}$ unit: lm/sr, cd	The luminous intensity of a point light source in a defined direction is the quotient of the emitted luminous flux to the corresponding solid angle element.

Designation of the radiation	Abbreviation	Wavelength $\lambda[\text{nm}]$	Photon energy [eV]	Detector (examples)
ultra-violet radiation Vacuum-UV Far UV Mid UV Near UV	UV UV-C < FUV UV-B UV-A	100 to 200 200 to 280 280 to 315 315 to 400	12,4 to 6,2 6,2 to 4,4 4,4 to 3,9 3,9 to 3,1	Cs-I, Cs-Te SiC
Visible radiation, light	VIS	380 to 780	3,3 to 1,6	Alkali PMT Si
Infrared radiation Near IR Mid IR Near IR	IR NIR < IR-A IR-B IR-C < MIR FIR	780 to 1400 1400 to 3000 3000 to $5 \cdot 10^4$ $5 \cdot 10^4$ to 10^6	1,6 to 0,9 0,9 to 0,4 0,4 to 0,025 0,025 to 0,001	Si, Ge, InGaAs InAs PbSnTe, PbSnSe